

CMST2907A
SURFACE MOUNT
PNP SILICON TRANSISTOR

SUPERmini™



SOT-323 CASE



www.centrasemi.com

DESCRIPTION:

The CENTRAL SEMICONDUCTOR CMST2907A type is a PNP silicon transistor manufactured by the epitaxial planar process, epoxy molded in a SUPERmini™ surface mount package, designed for small signal, general purpose and switching applications.

MARKING CODE: 2FC

MAXIMUM RATINGS: ($T_A=25^\circ\text{C}$)

Collector-Base Voltage
Collector-Emitter Voltage
Emitter-Base Voltage
Continuous Collector Current
Power Dissipation
Operating and Storage Junction Temperature
Thermal Resistance

SYMBOL		UNITS
V_{CBO}	60	V
V_{CEO}	60	V
V_{EBO}	5.0	V
I_C	600	mA
P_D	275	mW
T_J, T_{stg}	-65 to +150	$^\circ\text{C}$
Θ_{JA}	455	$^\circ\text{C/W}$

ELECTRICAL CHARACTERISTICS: ($T_A=25^\circ\text{C}$ unless otherwise noted)

SYMBOL	TEST CONDITIONS	MIN	MAX	UNITS
I_{CBO}	$V_{CB}=50\text{V}$		10	nA
I_{CBO}	$V_{CB}=50\text{V}, T_A=125^\circ\text{C}$		10	μA
I_{CEV}	$V_{CE}=30\text{V}, V_{EB}=0.5\text{V}$		50	nA
BV_{CBO}	$I_C=10\mu\text{A}$	60		V
BV_{CEO}	$I_C=10\text{mA}$	60		V
BV_{EBO}	$I_E=10\mu\text{A}$	5.0		V
$V_{CE(SAT)}$	$I_C=150\text{mA}, I_B=15\text{mA}$		0.4	V
$V_{CE(SAT)}$	$I_C=500\text{mA}, I_B=50\text{mA}$		1.6	V
$V_{BE(SAT)}$	$I_C=150\text{mA}, I_B=15\text{mA}$		1.3	V
$V_{BE(SAT)}$	$I_C=500\text{mA}, I_B=50\text{mA}$		2.6	V
h_{FE}	$V_{CE}=10\text{V}, I_C=0.1\text{mA}$	75		
h_{FE}	$V_{CE}=10\text{V}, I_C=1.0\text{mA}$	100		
h_{FE}	$V_{CE}=10\text{V}, I_C=10\text{mA}$	100		
h_{FE}	$V_{CE}=10\text{V}, I_C=150\text{mA}$	100	300	
h_{FE}	$V_{CE}=10\text{V}, I_C=500\text{mA}$	50		
f_T	$V_{CE}=20\text{V}, I_C=50\text{mA}, f=100\text{MHz}$	200		MHz

R4 (9-February 2010)

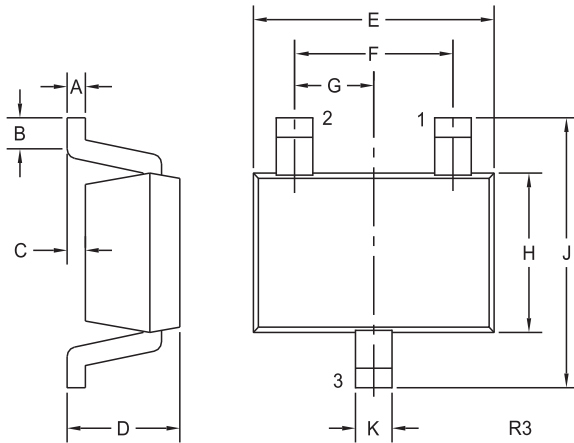
CMST2907A
SURFACE MOUNT
PNP SILICON TRANSISTOR



ELECTRICAL CHARACTERISTICS - Continued: ($T_A=25^{\circ}\text{C}$ unless otherwise noted)

SYMBOL	TEST CONDITIONS	MAX	UNITS
C_{ob}	$V_{CB}=10\text{V}$, $I_E=0$, $f=1.0\text{MHz}$	8.0	pF
C_{ib}	$V_{EB}=2.0\text{V}$, $I_C=0$, $f=1.0\text{MHz}$	30	pF
t_{on}	$V_{CC}=30\text{V}$, $V_{BE}=0.5$, $I_C=150\text{mA}$, $I_{B1}=15\text{mA}$	45	ns
t_d	$V_{CC}=30\text{V}$, $V_{BE}=0.5$, $I_C=150\text{mA}$, $I_{B1}=15\text{mA}$	10	ns
t_r	$V_{CC}=30\text{V}$, $V_{BE}=0.5$, $I_C=150\text{mA}$, $I_{B1}=15\text{mA}$	40	ns
t_{off}	$V_{CC}=6.0\text{V}$, $I_C=150\text{mA}$, $I_{B1}=I_{B2}=15\text{mA}$	100	ns
t_s	$V_{CC}=6.0\text{V}$, $I_C=150\text{mA}$, $I_{B1}=I_{B2}=15\text{mA}$	80	ns
t_f	$V_{CC}=6.0\text{V}$, $I_C=150\text{mA}$, $I_{B1}=I_{B2}=15\text{mA}$	30	ns

SOT-323 CASE - MECHANICAL OUTLINE



SYMBOL	DIMENSIONS			
	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.002	0.008	0.05	0.20
B	0.004	-	0.10	-
C	-	0.004	-	0.10
D	0.031	0.043	0.80	1.10
E	0.071	0.087	1.80	2.20
F	0.051		1.30	
G	0.026		0.65	
H	0.045	0.053	1.15	1.35
J	0.079	0.087	2.00	2.20
K	0.008	0.016	0.20	0.40

SOT-323 (REV: R3)

LEAD CODE:

- 1) Base
- 2) Emitter
- 3) Collector

MARKING CODE: 2FC

R4 (9-February 2010)